Hex Inverting Schmitt Triggers

UT54ACS14/UT54ACTS14

Features

- 0.6μ CRH CMOS process
 - Latchup immune
- · High speed
- Low power consumption
- Single 5 volt supply
- Available QML Q or V processes
- 14-lead flatpack
- UT54ACS14 SMD 5962-96524
- UT54ACTS14 SMD 5962-96525

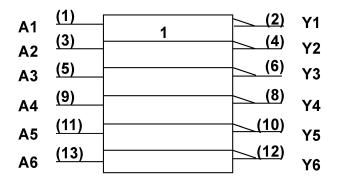
Description

The UT54ACS14 and the UT54ACTS14 are hex inverters. The circuits perform the Boolean function $Y = \bar{A}$. The devices are characterized over full military temperature range of -55°C to + 125°C.

Function Table

Input	Output
А	Υ
Н	L
L	Н

Logic Symbol

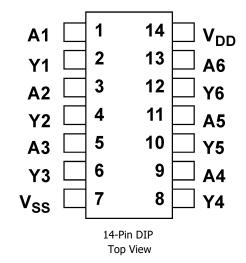


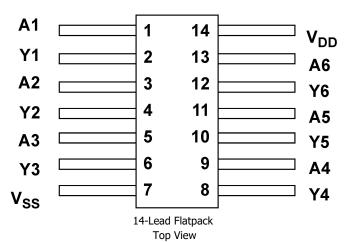
Note:

1) Logic symbol in accordance with ANSI/IEEE standard 91-1984 and IEC Publication 617-12.

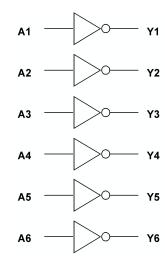


Pinouts





Logic Diagram





Operational Environment¹

Parameter	Limit	Units
Total Dose	5.0E5	rads(Si)
SEU Threshold ²	80	MeV-cm2/mg
SEL Threshold	120	MeV-cm2/mg
Neutron Fluence	1.0E14	n/cm2

Notes:

- 1) Logic will not latchup during radiation exposure within the limits defined in the table.
- 2) Device storage elements are immune to SEU affects.

Absolute Maximum Ratings

Symbol	ymbol Parameter Limit		Units
V_{DD}	Supply voltage	-0.3 to 7.0	V
V _{I/O}	Voltage any pin	3 to V _{DD} +.3	V
T _{STG}	Storage Temperature range -65 to +15		°C
T _J	Maximum junction temperature	+175	°C
T _{LS}	Lead temperature (soldering 5 seconds)	+300	°C
$\Theta_{ extsf{JC}}$	Thermal resistance junction to case	15.0 (ACS) 15.5 (ACTS)	°C/W
I _I	DC input current	±10	mA
P _D	Maximum power dissipation	1	W

Note:

1) Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other condition beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Limit	Units
V_{DD}	Supply voltage	4.5 to 5.5	V
V_{IN}	Input voltage any pin	0 to V_{DD}	V
T _C	Temperature range	-55 to + 125	°C



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DC Electrical Characteristics ⁷

 $(V_{DD} = 5.0V \pm 10\%; V_{SS} = 0V 6, -55^{\circ}C < T_{C} < +125^{\circ}C);$ Unless otherwise noted, Tc is per the temperature range ordered.

Symbol	Parameter		Condition	MIN	MAX	Unit
V _{T+}	Schmitt Trigger, positive going ¹ threshold ACTS ACS				2.25 .7V _{DD}	V
V _T -	Schmitt Trigger, no ACTS ACS	egative going ¹ threshold		0.5 .3V _{DD}		\ \
V _H	Schmitt Trigger, ty ACTS ACS	pical range of hysteresis ²		0.4 0.6	1.5 1.5	V
${ m I}_{ m IN}$	Input leakage curr ACTS/ACS	rent	$V_{IN} = V_{DD}$ or V_{SS}	-1	1	μА
V _{OL}	Low-level output voltage ³ ACTS ACS		$I_{OL}=8.0$ mA $I_{OL}=100$ μ A		0.40 0.25	V
V _{OH}	High-level output voltage ³ ACTS ACS		I _{OH} = -8.0mA I _{OH} = -100μA	.7V _{DD} V _{DD} -0.25		V
I_{OS}	Short-circuit output current ^{2, 4} ACTS/ACS		$V_{O} = V_{DD}$ and V_{SS}	-200	200	mA
${ m I}_{ m OL}$	Output current ¹⁰ (Sink)		$V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{OL} = 0.4V$	8		mA
I_{OH}	Output current ¹⁰ (Source)		$V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{OH} = V_{DD} - 0.4V$	-8		mA
P _{total}	Power dissipation ^{2, 8, 9} ACTS ACS		CL = 50pF		1.9 1.8	mW / MHz
	Quiescent	Pre-Rad			10	
I_{DDQ}	Supply Current	Post-Rad Device Type 01	$V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = V_{DD} \text{ MAX}$		50	μΑ
ΔI_{DDQ}	Quiescent Supply Current Delta ACTS		For input under test $V_{IN} = V_{DD} - 2.1V$ For all other inputs $V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = 5.5V$		3.1	mA
C_{IN}	Input capacitance ⁵		f = 1MHz @ 0V		15	pF
C _{OUT}	Output capacitance ⁵		f = 1MHz @ 0V		15	pF



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Notes:

- 1) Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions: $V_{IH} = V_{IH}(min) + 20\%$, 0%; $V_{IL} = V_{IL}(max) + 0\%$, 50%, as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to $V_{IH}(min)$ and $V_{IL}(max)$.
- 2) Supplied as a design limit but not guaranteed or tested.
- 3) Per MIL-PRF-38535, for current density ≤ 5.0E5 amps/cm², the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765 pF/MHz
- 4) Not more than one output may be shorted at a time for maximum duration of one second.
- 5) Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and V_{SS} at frequency of 1MHz and a signal amplitude of 50mV rms maximum.
- 6) Maximum allowable relative shift equals 50mV.
- 7) Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.
- 8) Power does not include power contribution of any TTL output sink current.
- 9) Power dissipation specified per switching output.
- 10) This value is guaranteed based on characterization data, but not tested.

AC Electrical Characteristics ²

 $(V_{DD} = 5.0V \pm 10\%; V_{SS} = 0V 1, -55^{\circ}C < T_{C} < +125^{\circ}C);$ Unless otherwise noted, Tc is per the temperature range ordered.

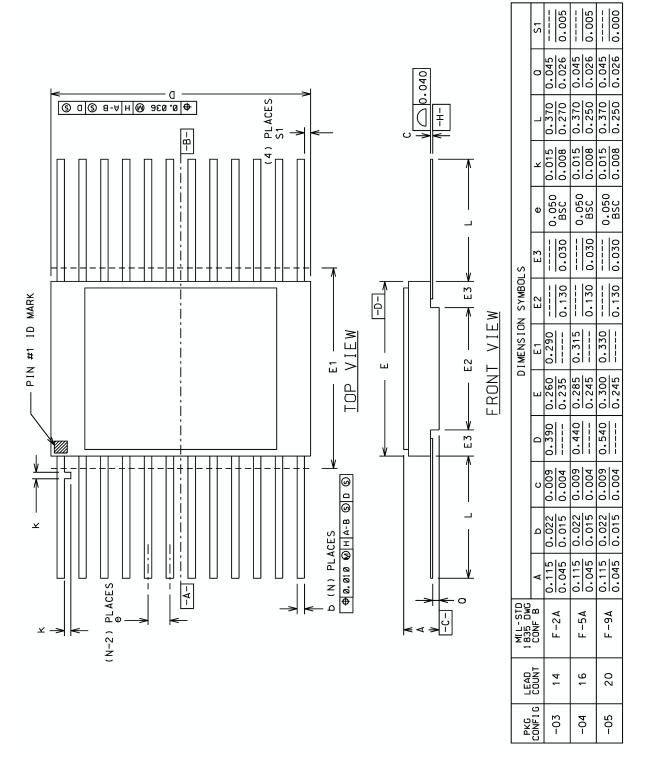
Symbol	Parameter	Minimum	Maximum	Unit
t _{PHL}	Input to Yn ACS ACTS	2 2	14 12	ns
t _{РLН}	Input to Yn ACS ACTS	2 2	13 9	ns

Notes:

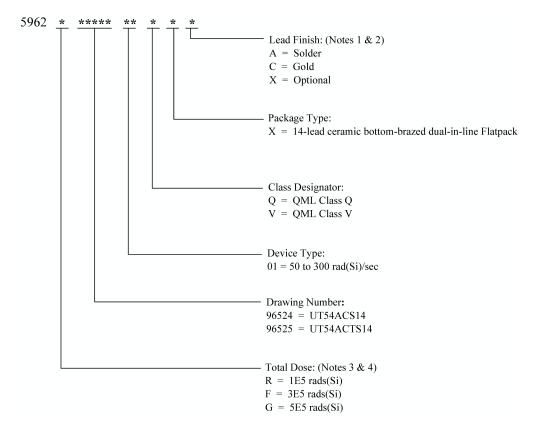
- 1) Maximum allowable relative shift equals 50mV.
- 2) Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.



Packages



UT54ACS14/UT54ACTS14: SMD



Notes:

- 1) Lead finish (A, C, or X) must be specified.
- 2) If an "X" is specified when ordering, part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
- 3) Total dose radiation must be specified when ordering. QML Q and QML V not available without radiation hardening. For prototype inquiries, contact factory.
- 4) Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.

Data Sheet Revision History

Revision Date	Description of Change	Author
	Page 4 edited IDDQ and PTOTAL	
10-17	Page 5 edited AC Electricals	RT
	Applied new CAES Data Sheet template to the document.	
1-18 Updates to reflect current SMD		RT



Datasheet Definitions

Datasheet Definitions			
	DEFINITION		
Advanced Datasheet	CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is still in the development stage and the datasheet is subject to change. Specifications can be TBD and the part package and pinout are not final.		
Preliminary Datasheet	CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is in the characterization stage and prototypes are available.		
Datasheet	Product is in production and any changes to the product and services described herein will follow a formal customer notification process for form, fit or function changes.		

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